Product Specifications

PLASTIC FILM CHIP CAPACITOR TYPE ECHU(X)

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NO.	1-17	
Revision Code	R0	
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		This specification covers the require	ment for metallized polyphenylene	sulfide dielectric fixed
1. S	COPE	chip capacitor for use in electronic equipments.		
2. P	RODUCT NAME	Plastic film chip capacitor Type ECHU(X)		
		Operating temperature range	Operating temperature range	
3.PF	RODUCT RANGE	Rated voltage	16 VDC (1C)	50VDC (1H)
-		Capacitance range	0.00010 µF to 0.10 µF 0.0	0010 µF to 0.039 µF
		Capacitance tolerance	±2% (G), ±5% (J)	
4. C S	onditional Tandard test	The test shall be conducted at temperature from 15°C to 35°C, relative humidity from 45% to 75% (standard test conditions). EST However the test shall be conducted at temperature of 20°C \pm 2°C, relative humidity of 65% \pm 5% (strict test conditions), when doubt is entertained about judgment.		
5. S M	OLDERING ETHOD	Reflow method only		
6. C	ONSTRUCTION	The capacitor has a non-inductive construction, stacked with one side metallized polyphenylene sulfide film. The capacitor has outer electrode on both sides. element (polyphenylene sulfide) Outer electrode Base material :copper alloy, conductive resin Plating material :Pb-free solder (Sn-Ag-Cu)		
7. DIMENSIONS		As specified in the individual drawing	g.	
8. APPEARANCE 1. Capacitor sha 2. Plating of oute		 Capacitor shall be perfect without Plating of outer electrode shall be 	cut or turned up film. perfect without defect or rust that	matters practical use.
9. C	HARACTER			
No.	ltem	Perfor	mance	Test Method
1.	Dielectric Withstand Voltage	Between terminals: Nothing abnormal shall be for 150% of the rated voltage for for 1 s to 5 s. However self-healing is not ab (The capacitor shall be applied 2 kΩ when charge and dischard	ound, when applied a voltage of 1 min or 175% of the rated voltag normal. I the voltage through more than rge.)	f JIC C 5102-1994 7.1 IEC 384-1-1982 4.6
2.	Insulation Resistance	Between terminals : 3000 MΩ or more When the reading of measurin value after applying a voltage of DC 10 V ±1.5 V for 1 min ±5 s, DC 50 V ±1.5 V for 1 min ±5 s,	g instrument becomes steady at a of , at 20°C ±2°C (1C), , at 20°C ±2°C (1H)	JIC C 5102-1994 7.6 IEC 384-1-1982 4.5

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No.	Item	Performance	Test Method
3.	Capacitance	Within a range of specified value. (Measured at a frequency of 1 kHz ±0.2 kHz, at 20°C ±2°C and with voltage of 5 Vrms or less.)	JIC C 5102-1994 7.8 IEC 384-1-1982
4.	Dissipation Factor	0.6% or less (Measured at a frequency of 1 kHz ±0.2 kHz, at 20°C ±2°C and with voltage of 5 Vrms or less.)	JIC C 5102-1994 7.9 IEC 384-1-1982 4.8
5.	Connection	The connection of the element shall not open even instantaneously when applied a voltage of 100 mV peak or less and applied light force.	JIS C 5102-1994 7.10 IEC 384-1-1982
6.	Vibration Resistance	The capacitor shall be mounted on the PCB (Printed Circuit Board), and the following vibration shall be applied to the capacitor. Range of vibration frequency 10 Hz to 55 Hz total amplitude 1.5 mm, rate of frequency vibration to be such as varying from 10 Hz to 55 Hz and return to 10 Hz in about 1 min and thus repeated. Thus shall be conducted for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours). The connection shall not get short-circuit or open when examined the connection of the element in compliance with the previous item (connection of element) during the last 30 min of the test.	JIC C 5102-1994 8.2.3.(A) IEC 384-1-1982 4.17
7.	Soldering Property	The terminal shall be immersed in methanol solution of resin (about 25%) and the terminal shall be immersed in the solder bath at a temperature of 255°C ±5°C for 2.5 s ±0.5 s. After test immersion, the solder shall be stuck to 90% or more in the surface of the electrode that shown in blew development. $\underbrace{X \text{ mm}}_{X \text{ mm}} \underbrace{X \text{ mm}} $	JIS C 5102-1994 8.4 IEC 384-1-1982 4.15

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No.	Item	Performance	Test Method
8.	Moisture Resistance (I)	The capacitor under test shall be kept at condition of the temperature 40°C \pm 2°C and the humidity at 90%RH to 95%RH for 1000 hours \pm 48/ -0 hours in the testing oven and then kept at ordinary condition (ordinary temperature and humidity) for 1.5 hours \pm 0.5 hours. After the test, the capacitor shall be satisfied with the following performance. Appearance : No remarkable change. Dielectric Withstand Voltage : Between terminals Nothing abnormal shall be found, when applied a voltage of 130% of the rated voltage for 1 min (the capacitor shall be applied the voltage through 2 k Ω or more when charge and discharge). Insulation Resistance : Between terminals 1000 M Ω or more Change rate of capacitance : Within \pm 2% of the value before the test. Dissipation Factor: 0.9% or less (at 1 kHz)	JIC C 5102-1994 9.5 IEC 384-1-1982 4.22
9.	Moisture Resistance (II)	The capacitor under test shall be kept at condition of the temperature 60°C \pm 2°C and the humidity at 90%RH to 95%RH for 500 +24/ -0 hours in the testing oven and then kept at ordinary condition for 1.5 hours \pm 0.5 hours. After the test, the capacitor shall be satisfied with the following performance. Appearance : No remarkable change. Dielectric Withstand Voltage : Between terminals Nothing abnormal shall be found, when applied a voltage of 130% of the rated voltage for 1 min (the capacitor shall be applied the voltage through more than 2 k Ω when charge and discharge). Insulation Resistance : Between terminals 500 M Ω or more Change rate of capacitance : Within \pm 2% of the value before the test. Dissipation Factor : 0.9% or less (at 1 kHz)	JIC C 5102-1994 9.5 IEC 384-1-1982 4.22

Standard Doc. PLASTIC FILM CHIP CAPACITOR 1 - 17Product Revision TYPE ECHU(X) R0 Specifications Code P. 4 / 20 No. Item Performance Test Method The capacitor under test shall be kept at condition of the temperature 40°C ±2°C and the humidity at 90%RH to 95%RH with applying the rated voltage continuously for 1000 hours +48/ -0 hours in the testing oven and then kept at ordinary condition for 1.5 hours ±0.5 hours. After the test, the capacitor shall be satisfied with the following performance. Appearance : No remarkable change. Dielectric Withstand Voltage : Moisture Resistance JIC C 5102-1994 10. Between terminals Loading (I) 9.9 Nothing abnormal shall be found, when applied a voltage of 130% of the rated voltage for 1 min (the capacitor shall be applied the voltage through more than 2 k Ω when charge and discharge). Insulation Resistance : Between terminals $1000 M\Omega$ or more Change rate of capacitance : Within ±2% of the value before the test. **Dissipation Factor :** 0.9% or less (at 1 kHz) The capacitor under test shall be kept at condition of the temperature 60°C ±2°C and the humidity at 90%RH to 95%RH with applying the rated voltage continuously for 500 hours +24/ -0 hours in the testing oven and then kept at ordinary condition for 1.5 hours ±0.5 hours. After the test, the capacitor shall be satisfied with the following performance. Appearance : No remarkable change. Dielectric Withstand Voltage : Moisture Resistance JIC C 5102-1994 11. Between terminals Loading (II) 9.9 Nothing abnormal shall be found, when applied a voltage of 130% of the rated voltage for 1 min (the capacitor shall be applied the voltage through more than 2 k Ω when charge and discharge). Insulation Resistance : Between terminals 500 M Ω or more Change rate of capacitance : Within $\pm 2\%$ of the value before the test. **Dissipation Factor :** 0.9% or less (at 1 kHz)

Moisture Resistar	PLASTIC FILM CHIP CAPACITOR TYPE ECHU(X) Note Revise Performance The capacitor under test shall be kept at condition of the temperature 85°C ±2°C and the humidity at 85%RH +2/ -5%RH with applying the rated voltage continuously for 500 hours +24/ -0 hours in the testing oven and then kept at ordinary condition for 1.5 hours ±0.5 hours. After the test, the capacitor shall be satisfied with the following performance. Appearance : No remarkable change. Dielectric Withstand Voltage : Between terminals Nothing abnormal shall be found, when applied the rate voltage for 1 min (the capacitor shall be applied the voltage through more than 2 kΩ when charge and discharge). Insulation Resistance : Between terminals 10 MΩ or more Change rate of capacitance :	1-17 sion R0 5 / 20 P. Test Method
Product ecifications Item Moisture Resistar Loading (III)	TYPE ECHU(X) Revision of the temperature 85°C ±2°C and the humidity at 85%RH +2/ -5%RH with applying the rated voltage continuously for 500 hours +24/ -0 hours in the testing oven and then kept at ordinary condition for 1.5 hours ±0.5 hours. After the test, the capacitor shall be satisfied with the following performance. Appearance : No remarkable change. Dielectric Withstand Voltage : Between terminals Nothing abnormal shall be found, when applied the rate voltage for 1 min (the capacitor shall be applied the voltage through more than 2 kΩ when charge and discharge). Insulation Resistance : Between terminals 10 MΩ or more Change rate of capacitance :	sion R0 5 / 20 P. Test Method JIC C 5102-1994 9.9
Moisture Resistar	Performance The capacitor under test shall be kept at condition of the temperature 85°C ±2°C and the humidity at 85%RH +2/ -5%RH with applying the rated voltage continuously for 500 hours +24/ -0 hours in the testing oven and then kept at ordinary condition for 1.5 hours ±0.5 hours. After the test, the capacitor shall be satisfied with the following performance. Appearance : No remarkable change. Dielectric Withstand Voltage : Between terminals Nothing abnormal shall be found, when applied the rate voltage for 1 min (the capacitor shall be applied the voltage through more than 2 kΩ when charge and discharge). Insulation Resistance : Between terminals 10 MΩ or more Change rate of capacitance :	<u>5 / 20 P.</u> Test Method JIC C 5102-1994 9.9
Item Moisture Resistar Loading (III)	PerformanceThe capacitor under test shall be kept at condition of the temperature 85°C \pm 2°C and the humidity at 85%RH +2/ -5%RH with applying the rated voltage continuously for 500 hours +24/ -0 hours in the testing oven and then kept at ordinary condition for 1.5 hours \pm 0.5 hours.After the test, the capacitor shall be satisfied with the following performance.Appearance : No remarkable change.Dielectric Withstand Voltage : Between terminals Nothing abnormal shall be found, when applied the rate voltage for 1 min (the capacitor shall be applied the voltage through more than 2 k Ω when charge and discharge).Insulation Resistance : Between terminals 10 M Ω or more Change rate of capacitance :	Test Method JIC C 5102-1994 9.9
Moisture Resistar Loading (III)	The capacitor under test shall be kept at condition of the temperature 85°C $\pm 2^{\circ}$ C and the humidity at 85%RH $\pm 2/-5$ %RH with applying the rated voltage continuously for 500 hours $\pm 24/-0$ hours in the testing oven and then kept at ordinary condition for 1.5 hours ± 0.5 hours. After the test, the capacitor shall be satisfied with the following performance. Appearance : No remarkable change. Dielectric Withstand Voltage : Between terminals Nothing abnormal shall be found, when applied the rate voltage for 1 min (the capacitor shall be applied the voltage through more than 2 k Ω when charge and discharge). Insulation Resistance : Between terminals 10 M Ω or more Change rate of capacitance :	JIC C 5102-1994 9.9
	Within ±10% of the value before the test. Dissipation Factor : 1.2% or less (at 1 kHz)	
High Temperature	The capacitor under test shall be kept at condition of the temperature 125°C \pm 2°C with applying a voltage of 125% of the rated voltage through a series-connected resister of from 20 Ω to 1000 Ω per 1 V continuously for 1000 hours +48/ -0 hours in the testing oven and then let alone until the capacitor reaches the heat equilibrium with ordinary condition. After the test, the capacitor shall be satisfied with the following performance. Appearance : No remarkable change. Insulation Resistance : Between terminals 1000 M Ω or more Change rate of capacitance : Within \pm 2% of the value before the test. Dissipation Factor : 0.66% or less (at 1 kHz)	JIC C 5102-1994 9.10
Heat Resistance	The capacitor under test shall be kept at condition of the temperature at 125°C \pm 2°C for 2 hours \pm 1/ -0 hour in the testing oven. After the test, the capacitor shall be satisfied with the following performance. Insulation Resistance : Between terminals 100 M Ω or more Change rate of capacitance : Within \pm 3%/ -2% of the value before the test.	JIC C 5102-1994 9.2 IEC 384-1-1982 4.21.2
HL:	ligh Temperature oading Heat Resistance	temperature 125°C $\pm 2^{\circ}$ C with applying a voltage of 125% of the rated voltage through a series-connected resister of from 20 Ω to 1000 Ω per 1 V continuously for 1000 hours +48/-0 hours in the testing oven and then let alone until the capacitor reaches the heat equilibrium with ordinary condition. After the test, the capacitor shall be satisfied with the following performance. Appearance : No remarkable change. Insulation Resistance : Between terminals 1000 M Ω or more Change rate of capacitance : Within $\pm 2^{\circ}$ of the value before the test. Dissipation Factor : 0.66% or less (at 1 kHz) The capacitor under test shall be kept at condition of the temperature at 125°C $\pm 2^{\circ}$ C for 2 hours +1/-0 hour in the testing oven. After the test, the capacitor shall be satisfied with the following performance. Insulation Resistance : Between terminals 100 M Ω or more Change rate of capacitor shall be satisfied with the following performance. Insulation Resistance : Between terminals 100 M Ω or more Change rate of capacitance : Within +3%/-2% of the value before the test.

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15.	Cold Resistanc	The capacitor under test shall be kept at condition of the temperature at -55°C ±3°C for 2 hours +1/ -0 hour in the testing oven. e After the test, the capacitor shall be satisfied with the following performance. Change rate of capacitance : Within ±2% of the value before the test.	JIC C 5102-1994 9.1 IEC 384-1-1982 4.21.4
		 Reflow method Test condition of the reflow oven shall be adjusted that maximum temperature of the capacitor surface shall be 260°C ±3°C (see Fig.1). After this, the capacitor shall be satisfied with the following performance. 2 Saldaring imperational 	
		 2. Soldering iron method The soldering iron of a 30-watt shall be used and the temperature of the soldering iron shall be adjusted at 260°C ±10°C. The soldering iron together with a solder wire of 1mm diameter shall be put to each outer electrode of the capacitor for 3.5 s ±0.5 s. After this, the capacitor shall be satisfied with the following performance. 	
16.	Soldering Heat Resistance	Appearance : No remarkable change. Dielectric Withstand Voltage : Between terminals Nothing abnormal shall be found, when applied a voltage of 150% of the rated voltage for 1 min or 175% of the rated voltage for 1 s to 5 s. (The capacitor shall be applied the voltage through 2 kΩ or more when charge and discharge.) Insulation Resistance : Between terminals 1000 MΩ or more Change rate of capacitance : Within ±3% of the value before the test. Dissipation Factor : 0.66% or less (at 1 kHz) Connection : Stable	

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INO.	Item	Performance	iest method
17.	Temperature Cycle	The capacitor under the test shall be put in the testing oven and ker at condition of the temperature of -55° C $\pm 3^{\circ}$ C for 30 min ± 3 min ar then kept at the ordinary temperature for 3 min or less. After this, the capacitor under the test shall be kept at condition the temperature of 125° C $\pm 2^{\circ}$ C for 30 min ± 3 min and then kept the ordinary temperature for 3 min or less. These two operations shall be counted as 1 cycle, and it shall the repeated for 5 cycles successively. After the test, the capacitor shall be kept at the ordinary condition f 1.5 hours ± 0.5 hours, and shall be satisfied with the followin performance. Appearance : No remarkable change. Insulation Resistance : Between terminals 1000 M Ω or more Change rate of capacitance : Within $\pm 2^{\circ}$ of the value before the test. Dissipation Factor : 0.66% or less (at 1 kHz)	pt id of at or ig JIC C 5102-1994 9.3
18.	Robustness of Capacitor body	The equipment shall permit pressurizing. Apply a force to the center of specimen, using a pressurizing jig a shown in the drawing, for 10 s. The force shall be 5 N. Appearance : No remarkable change.	S JIS C 5102-1994 8.12

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19. Adhesive Strength		 Mount the specimen to the testing PCB. Examine the appearance of specimen with a magnifying glass of magnifications. As shown in below, apply the pressurizing jig to the center in the longitudinal direction of specimen. Apply a force to the pressurizing jig gradually in the horizontal direction with the testing PCB. The pressure shall be 5N (for 1608 size : 1N) and the holding duration for 10 s ±1 s. After the test, use a magnifying glass of 10 magnifications, and check for cracks of soldering position. 	10 JIC C	5102-1994 8.11.2
		Appearance : No remarkable change.		
20.	D.Resistance of Board to bendingThe bending stroke shall be 1 mm. Pressurizing shall be carried out at the rate of 1 mm/s. After reaching the specified bending, keep it for 5 s. After the test, no breaking of the terminal shall be found.		but t JIC C {	5102-1994 3.11.1



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10. A Caution about safety in use

I. Operating range (voltage, current, operating temperature)

Use the capacitor within the specified limits listed below (a to d). Over rated conditions might cause deterioration, damage, smoke and fire. Do not use capacitor beyond range of the condition.

- a) Permissible Voltage
 - DC rated voltage of this product is 50V (1H) and 16 V (1C). Use the capacitor within DC rated voltage.
 - When used in AC applied circuit, less than 30Vr.m.s. (1H) and 11Vr.m.s. (1C) should be applied.
 When used in a high frequency, less than 30Vr.m.s. (1H) and 11Vr.m.s. (1C) should be applied and current applied should be the value of permissible current in Fig.2 to 5 in page 17 to 20.
 - Do not apply to be in connected directly to AC line such as a primary power circuit.
 - Use the peak of pulse voltage applied the capacitor within the DC rated voltage.
 - · Caution about safety in inverter circuit for LCD back light use:

Do not use DC rated voltage 16V article for resonance uses, such as an inverter power supply for back lights of a liquid crystal display. Moreover, +B voltage of the following basic circuit should use DC rated voltage 50V article less than [9.5V]. And please use the peak of pulse voltage (especially, in case of the using PWM brightness circuit) applied the capacitor within the DC rated voltage.

[Typical electronic inverter circuit for LCD back light]



- b) Permissible Current
 - The permissible current must be considered by dividing into pulse current (peak current) and continuous current (rms current). When using, therefore, make sure the both current are within the permissible values.

In the case that a continuous current value is able not to be measured, use the capacitor within 10°C as the inherent temperature rise confirmed by the measuring method shown in page 16.

- Continuous current should be within specified figure in Fig.2 to 5. Contact us when the waveforms are totally different from the sine wave.
- Pulse current should be within the figures calculated by Tab.1. Use within 10000 cycles of pulse current. When pulse current applied more than 10000 cycles, please consult us before use.

c) Operating Temperature Range

- The specified "Operating Temperature Range" in specification is absolute maximum and minimum temperature rating. So in any case, each the capacitors shall be operated within the specified "Operating Temperature Range".
- It must be noted, however the "Operating Temperature Range" is the surface temperature of the capacitor is the sum of the ambient temperature + own temperature rise, not just the ambient temperature of the capacitor.
- If there is cooling plate of the other part of any resistance heated to high temperature near the capacitor, the capacitor may be locally heated by the radiation heat, exceeding the "Operating Temperature Range", and smoking or firing may be caused. Check the capacitor surface temperature at the heat source side.

d) For safety handling, check worst conditions within the specification range.

Protective means for safety should be provided in case the pulse and rms current may exceed the permissible values due to abnormal action of elsewhere in the circuit.

Please consult in advance when capacitors are connected in parallel to supplement capacitance.

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II. Recommendable land dimensions

For designing land dimensions, refer to the following recommendable land dimensions.

			unit: mm
Dimensions Size code	А	В	С
K1	0.6	2.0	0.7
J1, J2	0.8	2.4	1.1
H1, H2, H3	1.8	3.6	1.4
G1, G2, G3	1.8	3.6	2.3



<Note>

• A recommended solder paste thickness is between 0.10 mm and 0.15 mm.

III. Selection of Printed Circuit Board

Do not use ceramic and metal board, because they have a large thermal expansion coefficient that is different from that of this capacitor, which are liable to cause a deterioration of thermal cycle endurance.

IV. Soldering

a) Soldering method

This capacitor only used in reflow method. Don't use in flow, dipping, and VPS soldering method.

b) Recommendable reflow soldering conditions



<Note>

- The above figure is recommendable conditions.
- Soldering frequency shall be maximum two times. In soldering of second time, solder after capacitor body temperature returned to room temperature.
- When require further conditions except for the above, use within the range of test "Soldering Heat Resistance" shown in page 6.
- The reflow method recommends the hot wind circulation method. The heat influence on the capacitor is different in the methods other than the hot wind circulation method. Please confirm there is no problem in the characteristic of the capacitor beforehand when it is mounted excluding the hot wind circulation method. Please inquire when it is uncertain.

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c) Soldering conditions used in soldering iron

Temperature	Soldering time	Other conditions
max 270°C	max 4.0 s	Wattage of soldering iron: 30 W Pre-heating is not needed

• In the case of sketch (a)

Put a soldering iron to an electrode (for less than 4 s) with solder like sketch (a) shows. *Put soldering iron lightly.

*Soldering is allowed as one side by one side (without interval) or as both sides at the same time.

• In the case of sketch (b)

After a solder is melted on a soldering iron like sketch (b), put them to an electrode (for less than 4 s). *Put soldering iron lightly.

*Soldering is allowed as one side by one side (without interval) or as both sides at the same time.



<Note>

- Soldering frequency shall be maximum two times. In soldering of a second time, solder after capacitor body temperature returned for room temperature.
- The above condition shall be applied also on modifying by solder iron after reflow soldering. Modifying by solder iron after reflow soldering within once. Because there is heat career once by reflow soldering.
- When measuring temperature, it shall be operated with solder on soldering iron.
- Pay attention to the soldering iron tip not to touch directly to film dielectric, especially cut edge side.
- Consult with our engineering section in advance when require further conditions except for the above.

d) Others

- It is too much heat record that solders or solders removal this product or the other part which approaches this product using hot air-blow. Consult us before use.
- Do not to use soldering this product by light beam or laser beam. If used these method, consult us before using.
- Consult us before using, when soldering in other method.

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V. Soldering flux and solder

- The content of halogen in the flux of solder paste and solder wire shall be 0.1 wt% or less Rosin-based and non-activated soldering flux is recommended.
- Consult with our engineering section in advance when using flux with more than 0.1 wt% of the halogen content.

VI. Cleaning

a) Applicable solvent

Туре	Cleaner	Manufacturer
Alcohol	IPA (isopropyl alcohol)	General industrial use

b) Cleaning method

Item Conditions	Temperature	Period
Immersion	Room temperature	Within 5 min
Vaporized cleaning	Less than 50°C	Within 5 min
Ultrasonic cleaning	Less than 50°C	Within 5 min

<Note>

- Do not wash it with water.
- When cleaning after soldering, check temperature of capacitor surface is blew 60°C.
- It is necessary to remove cleaner from PCB by drying thoroughly after cleaning.
- Cleaner shall contain halogen within less than 0.1wt%, because in case of cleaning after mounting, halogen in flux will dissolve into cleaner.
- Consult with our engineering section in advance when further information for cleaning solvent, conditions are required.

VII. Storage and preservation

- It must be noted that the solderability of the external electrode may deteriorated when stored in an atmosphere filled with moisture, dust, or reactive gas such as hydrogen chloride, hydrogen sulfide, sulfurous acid, or ammonia etc.
- Avoid location with particularly high temperature and high humidity, and store in conditions not exceeding 35°C and 85%RH. Storage period limit is 6 months (use within 6 months).
- Consult with our engineering section in advance when require further conditions except for the above.

VIII. Operating environment

- Consult us about usage for a long period in humid environments, because characteristic deterioration by low insulation resistance or oxidization of metallized film may occur due to moisture absorption with the passing of the time.
- The Capacitor shall not be operated under following environmental conditions. These conditions may be generated to deteriorated the characteristic in the capacitor.
 - a) Under conditions of corrosive atmosphere such as hydrogen chloride, hydrogen sulfide, sulfurous acid, or ammonia etc.
 - b) Under conditions of water or frost formation.
 - c) To be exposed directly to water, oil, or sunlight.
 - d) To be exposed to ozone, radioactive rays, or ultraviolet rays.
- No dust should be permitted to remain on the surface of the product as this may cause electrical leakage.





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Tab.1 Permissible pulse current (Max 10000 cycles)

Pulse current applied to this capacitor should be used within permissible pulse current (Max 10000 cycles) shown in Tab.1 The pulse current = $C(\mu F) \times dV/dt$ value (V/µs)

In case of pulse current is over the specified table, inquire of our engineering section.

	dV/dt (V/ μs)	
Part No. (Capacitance: µF)	ECHU1C(X)	ECHU1H(X)
101 (0.00010)	420	1100
121 (0.00012)	390	1050
151 (0.00015)	350	940
181 (0.00018)	325	890
221 (0.00022)	295	800
271 (0.00027)	270	730
331 (0.00033)	245	690
391 (0.00039)	225	610
471 (0.00047)	205	580
561 (0.00056)	193	520
681 (0.00068)	175	480
821 (0.00082)	160	440
102 (0.0010)	150	400
122 (0.0012)	135	370
152 (0.0015)	123	340
182 (0.0018)	115	310
222 (0.0022)	105	270
272 (0.0027)	95	260
332 (0.0033)	86	240
392 (0.0039)	80	220
472 (0.0047)	74	200
562 (0.0056)	68	190
682 (0.0068)	62	170
822 (0.0082)	58	160
103 (0.010)	52	145
123 (0.012)	48	135
153 (0.015)	43	120
183 (0.018)	40	110
223 (0.022)	37	100
273 (0.027)	33	94
333 (0.033)	31	86
393 (0.039)	28	78
473 (0.047)	26	
563 (0.056)	24	
683 (0.068)	22	
823 (0.082)	20	
104 (0.10)	19	



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